

BC846, BC847, BC848

General Purpose Transistors

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SC-70/SOT-323 which is designed for low power surface mount applications.

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector-Emitter Voltage | V_{CEO} | | V |
| BC846 | | 65 | |
| BC847 | | 45 | |
| BC848 | | 30 | |
| Collector-Base Voltage | V_{CBO} | | V |
| BC846 | | 80 | |
| BC847 | | 50 | |
| BC848 | | 30 | |
| Emitter-Base Voltage | V_{EBO} | | V |
| BC846 | | 6.0 | |
| BC847 | | 6.0 | |
| BC848 | | 5.0 | |
| Collector Current – Continuous | I_C | 100 | mAdc |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

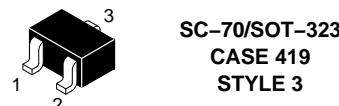
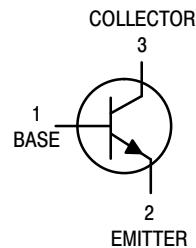
| Characteristic | Symbol | Max | Unit |
|---|-----------------|-------------|------|
| Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ | P_D | 200 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 620 | °C/W |
| Junction and Storage Temperature | T_J, T_{stg} | -55 to +150 | °C |

1. FR-5 = 1.0 x 0.75 x 0.062 in.

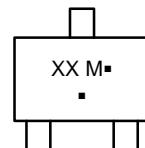


ON Semiconductor®

www.onsemi.com



MARKING DIAGRAM



XX = Specific Device Code
M = Month Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 12 of this data sheet.

BC846, BC847, BC848

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|--|---------------------------------------|-------------------|-------------------|---------------------|
| OFF CHARACTERISTICS | | | | | |
| Collector–Emitter Breakdown Voltage ($I_C = 10 \text{ mA}$) | $V_{(\text{BR})\text{CEO}}$ | 65 45 30 | — — — | — — — | V |
| Collector–Emitter Breakdown Voltage ($I_C = 10 \mu\text{A}$, $V_{EB} = 0$) | $V_{(\text{BR})\text{CES}}$ | 80 50 30 | — — — | — — — | V |
| Collector–Base Breakdown Voltage ($I_C = 10 \mu\text{A}$) | $V_{(\text{BR})\text{CBO}}$ | 80 50 30 | — — — | — — — | V |
| Emitter–Base Breakdown Voltage ($I_E = 1.0 \mu\text{A}$) | $V_{(\text{BR})\text{EBO}}$ | 6.0 6.0 5.0 | — — — | — — — | V |
| Collector Cutoff Current ($V_{CB} = 30 \text{ V}$) ($V_{CB} = 30 \text{ V}$, $T_A = 150^\circ\text{C}$) | I_{CBO} | — — | — — | 15 5.0 | nA μA |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain ($I_C = 10 \mu\text{A}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) | $\text{BC846A, BC847A, BC848A}$ $\text{BC846B, BC847B, BC848B}$ BC847C, BC848C $\text{BC846A, BC847A, BC848A}$ $\text{BC846B, BC847B, BC848B}$ BC847C, BC848C | h_{FE} — — — | 90 150 270 | — — — | — — — |
| Collector–Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$) | $V_{CE(\text{sat})}$ | — — | 110 200 420 | 180 290 520 | 220 450 800 |
| Base–Emitter Saturation Voltage ($I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}$, $I_B = 5.0 \text{ mA}$) | $V_{BE(\text{sat})}$ | — — | 0.7 0.9 | — — | V |
| Base–Emitter Voltage ($I_C = 2.0 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$) | $V_{BE(\text{on})}$ | 580 — | 660 — | 700 770 | mV |
| SMALL-SIGNAL CHARACTERISTICS | | | | | |
| Current–Gain – Bandwidth Product ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $f = 100 \text{ MHz}$) | f_T | 100 | — | — | MHz |
| Output Capacitance ($V_{CB} = 10 \text{ V}$, $f = 1.0 \text{ MHz}$) | C_{obo} | — | — | 4.5 | pF |
| Noise Figure ($I_C = 0.2 \text{ mA}$, $V_{CE} = 5.0 \text{ Vdc}$, $R_S = 2.0 \text{ k}\Omega$, $f = 1.0 \text{ kHz}$, $BW = 200 \text{ Hz}$) | NF | — | — | 10 | dB |

BC846, BC847, BC848

BC846A, BC847A, BC848A

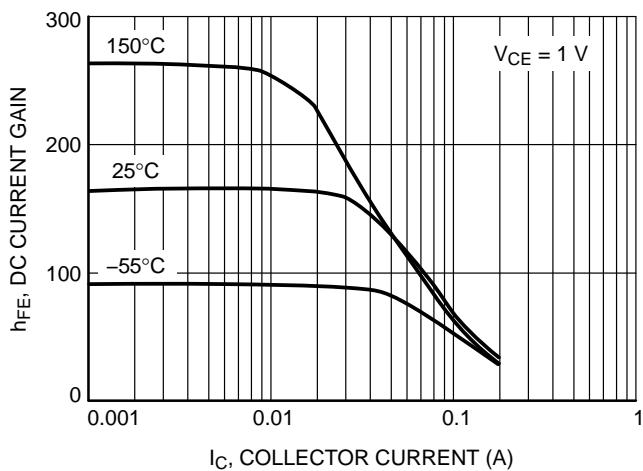


Figure 1. DC Current Gain vs. Collector Current

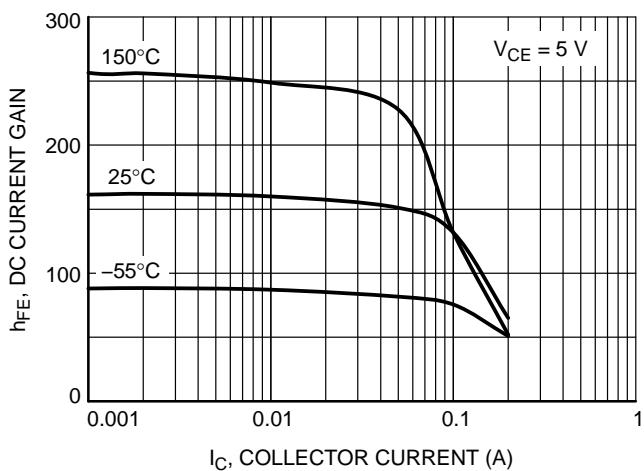


Figure 2. DC Current Gain vs. Collector Current

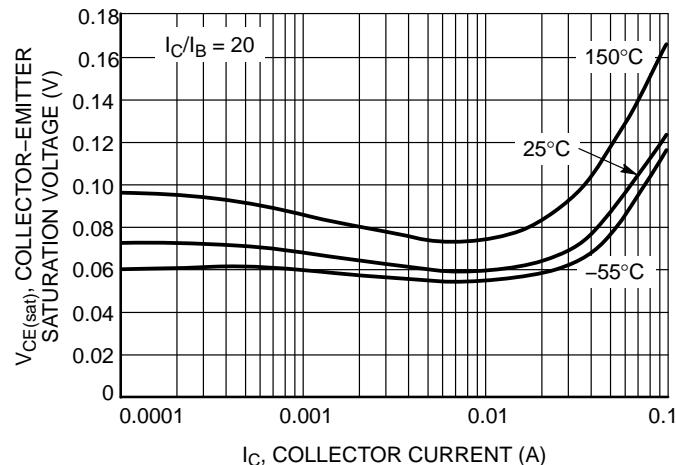


Figure 3. Collector Emitter Saturation Voltage vs. Collector Current

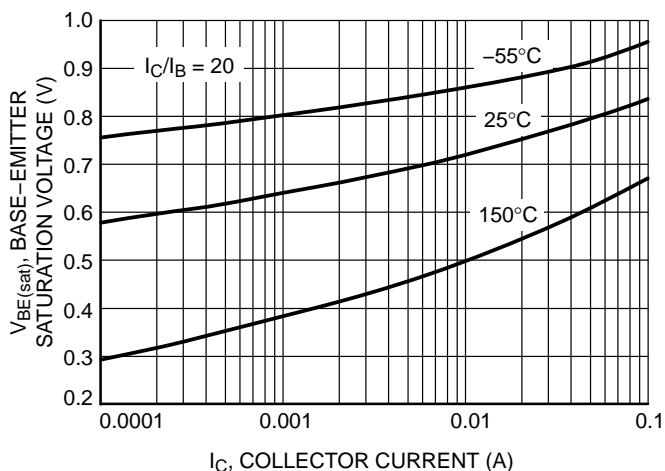


Figure 4. Base Emitter Saturation Voltage vs. Collector Current

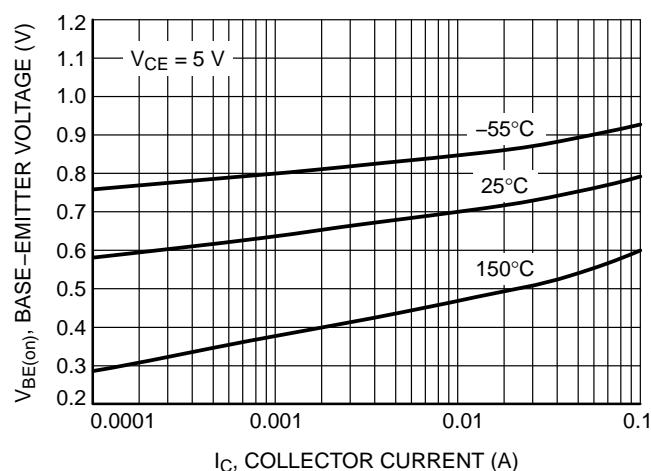


Figure 5. Base Emitter Voltage vs. Collector Current

BC846, BC847, BC848

BC846A, BC847A, BC848A

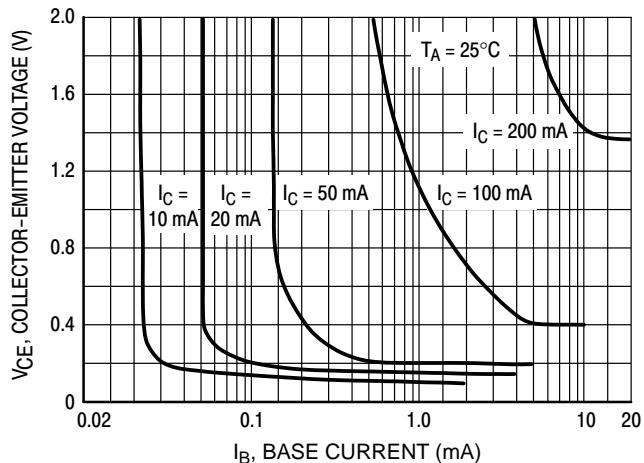


Figure 6. Collector Saturation Region

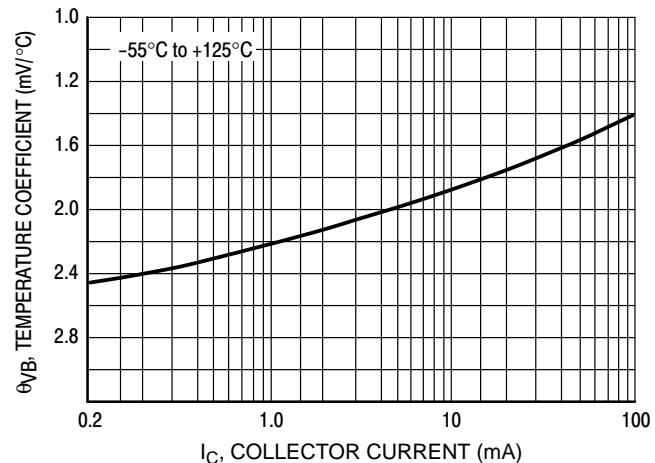


Figure 7. Base-Emitter Temperature Coefficient

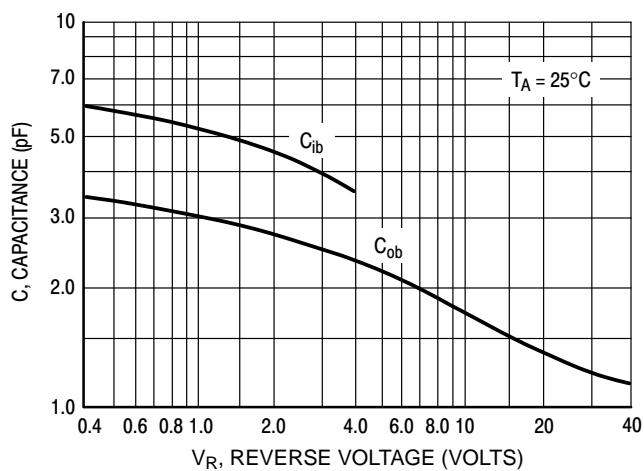


Figure 8. Capacitances

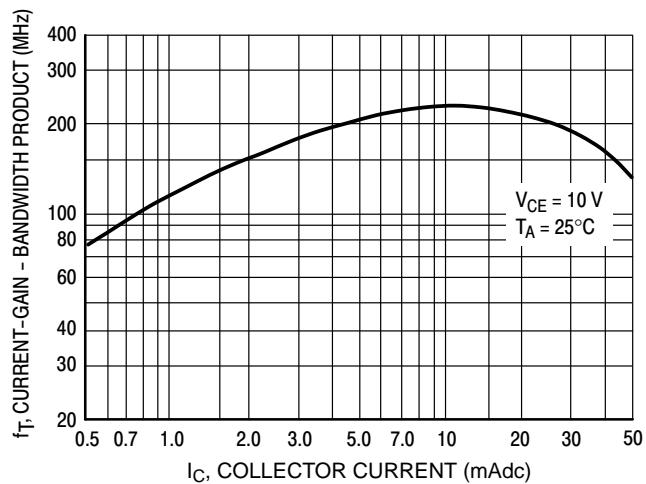


Figure 9. Current-Gain – Bandwidth Product

BC846, BC847, BC848

BC846B

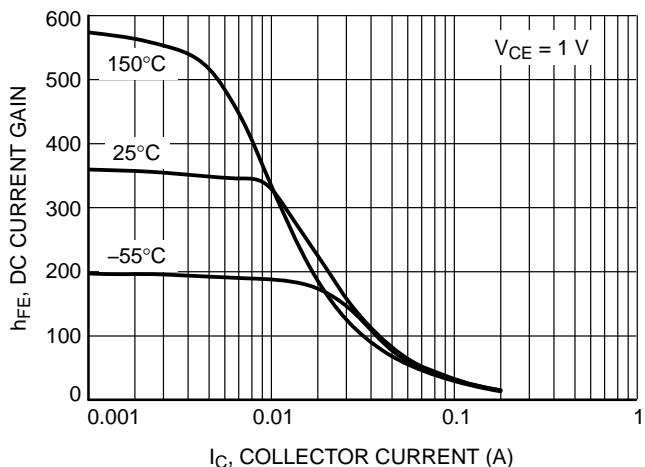


Figure 10. DC Current Gain vs. Collector Current

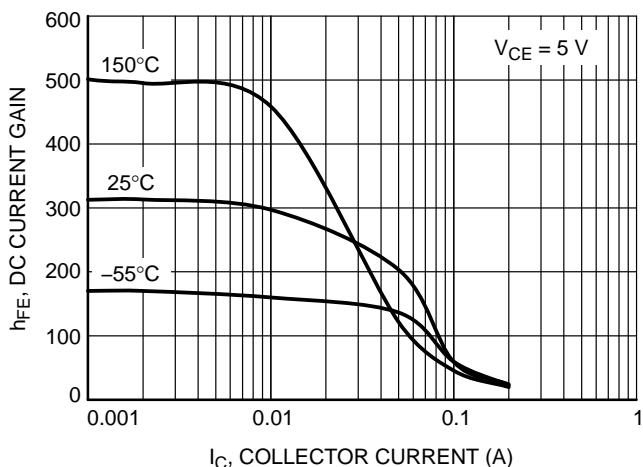


Figure 11. DC Current Gain vs. Collector Current

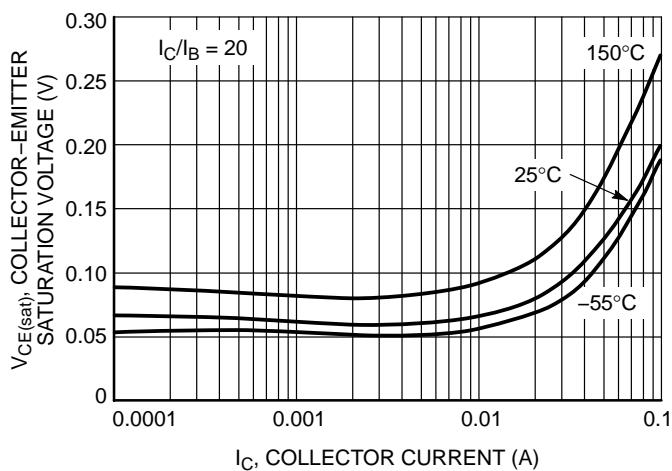


Figure 12. Collector Emitter Saturation Voltage vs. Collector Current

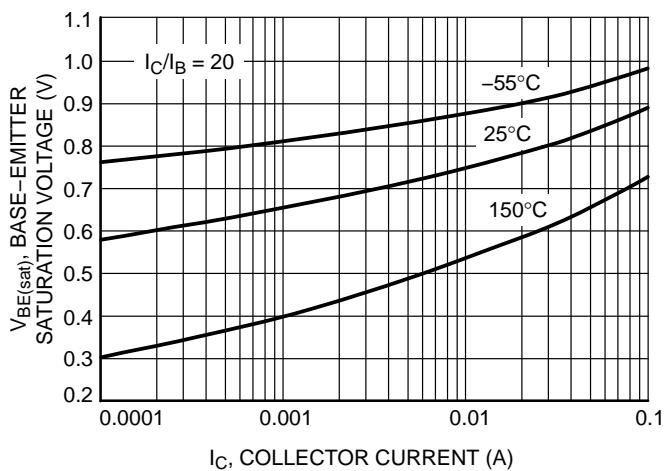


Figure 13. Base Emitter Saturation Voltage vs. Collector Current

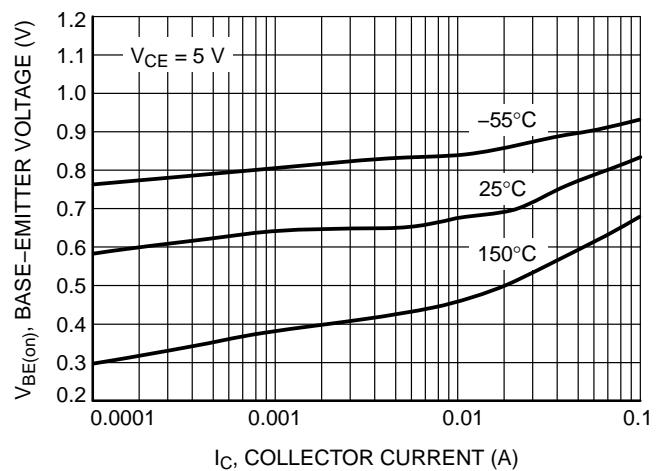


Figure 14. Base Emitter Voltage vs. Collector Current

BC846, BC847, BC848

BC846B

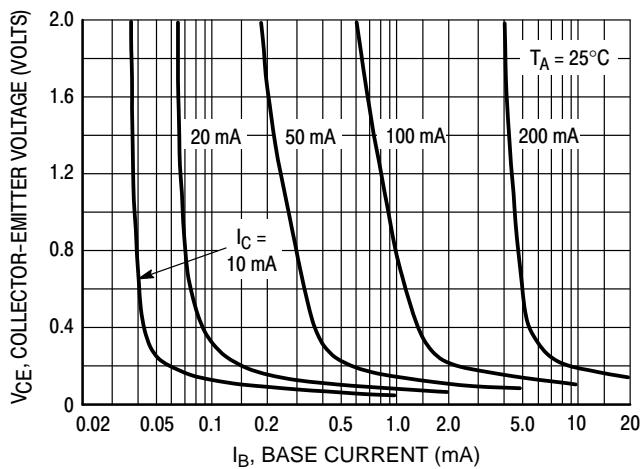


Figure 15. Collector Saturation Region

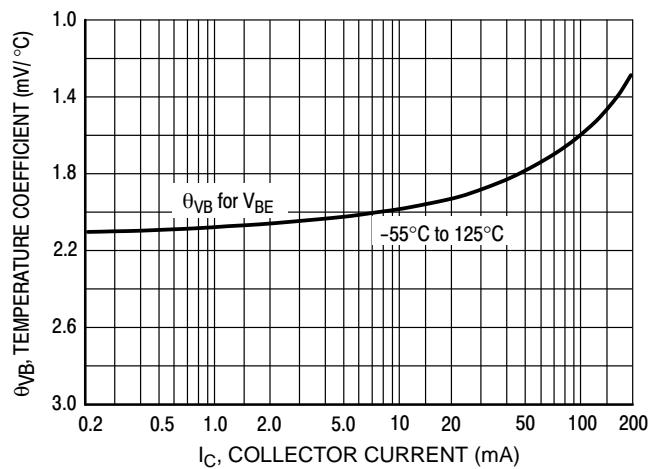


Figure 16. Base-Emitter Temperature Coefficient

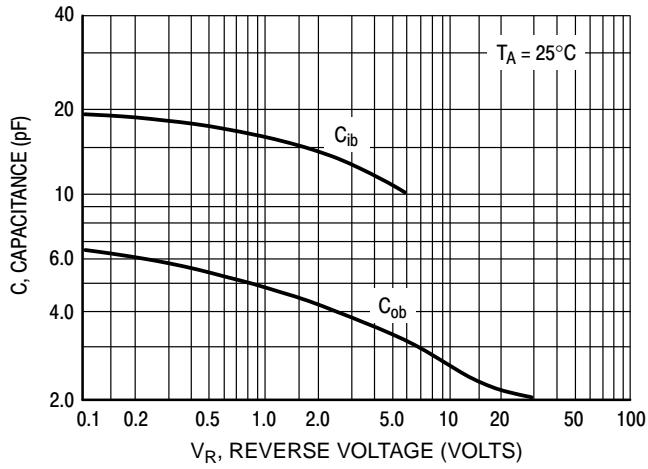


Figure 17. Capacitance

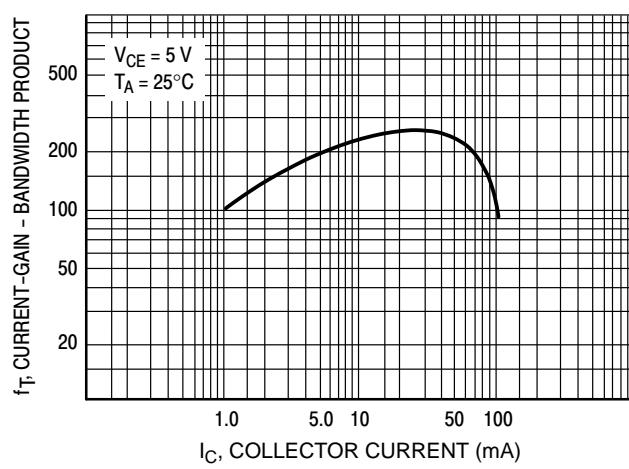


Figure 18. Current-Gain – Bandwidth Product

BC846, BC847, BC848

BC847B, BC848B

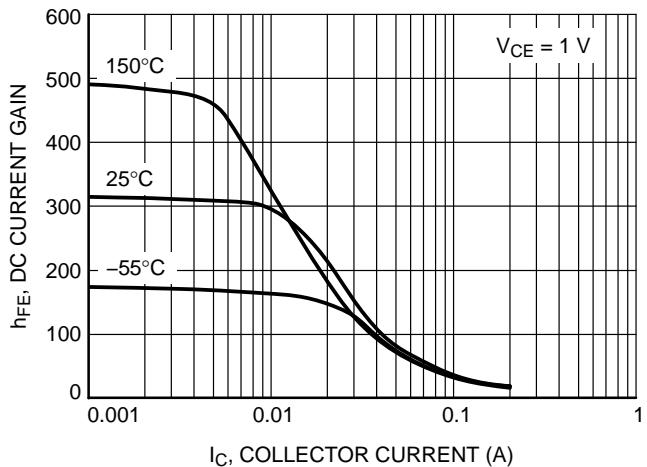


Figure 19. DC Current Gain vs. Collector Current

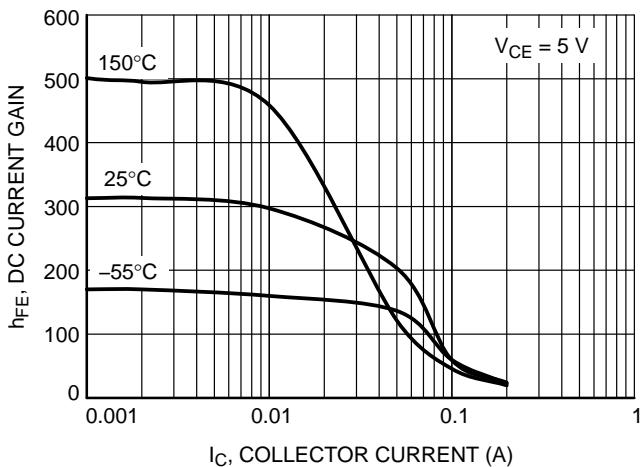


Figure 20. DC Current Gain vs. Collector Current

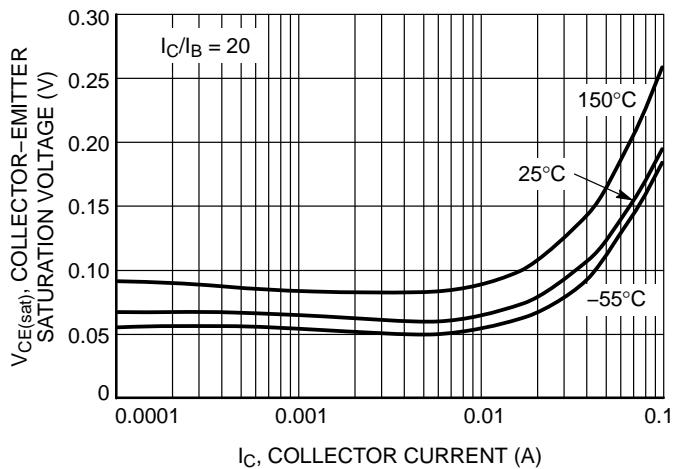


Figure 21. Collector Emitter Saturation Voltage vs. Collector Current

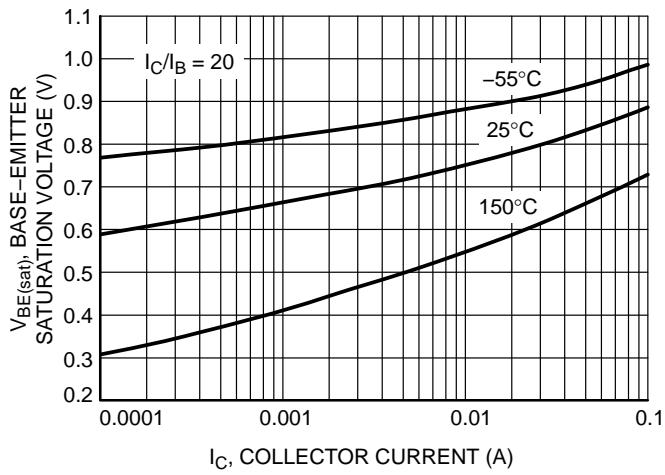


Figure 22. Base Emitter Saturation Voltage vs. Collector Current

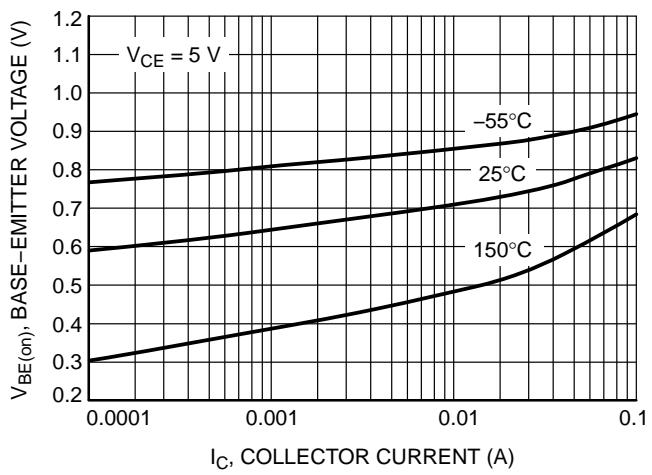


Figure 23. Base Emitter Voltage vs. Collector Current

BC846, BC847, BC848

BC847B, BC848B

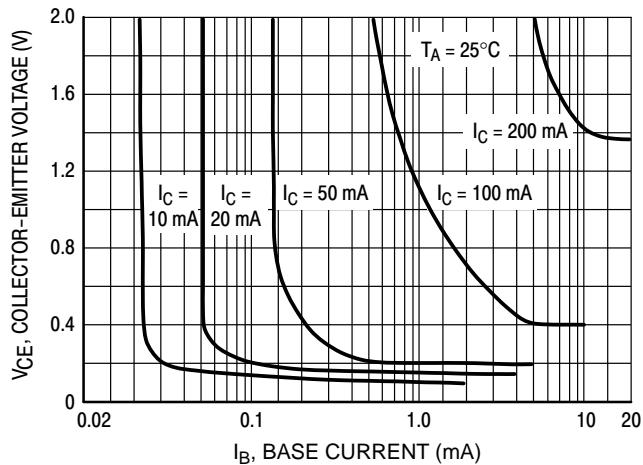


Figure 24. Collector Saturation Region

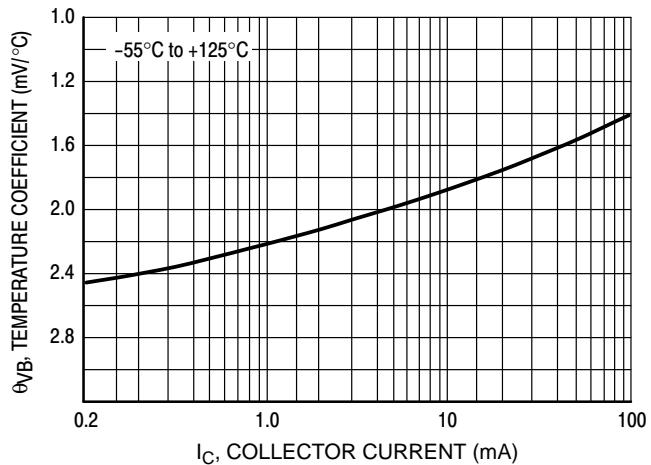


Figure 25. Base-Emitter Temperature Coefficient

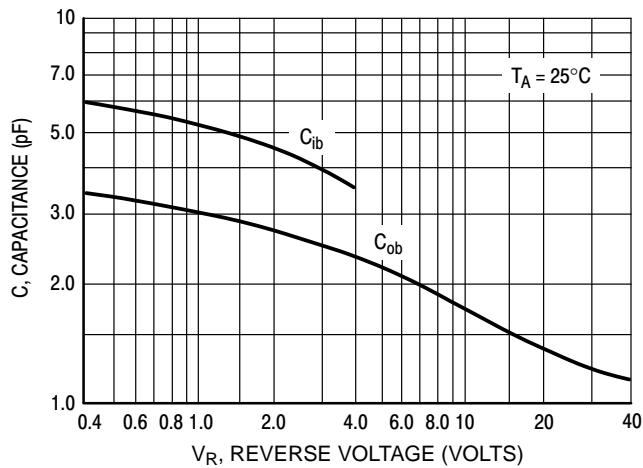


Figure 26. Capacitances

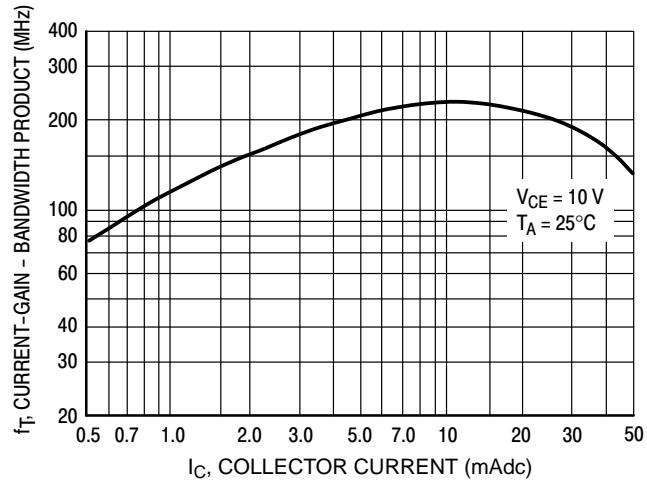


Figure 27. Current-Gain – Bandwidth Product

BC846, BC847, BC848

BC847C, BC848C

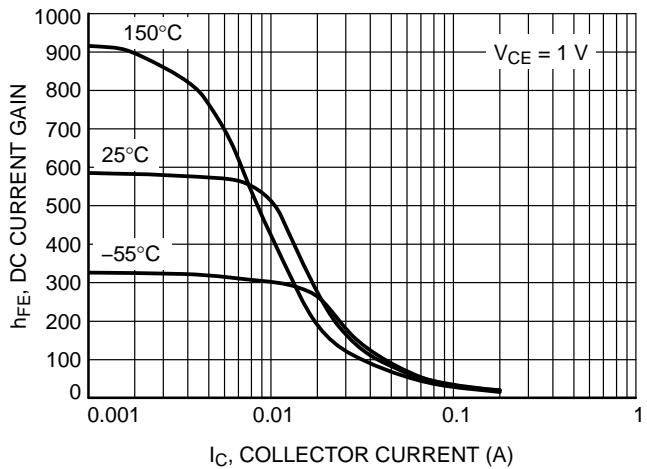


Figure 28. DC Current Gain vs. Collector Current

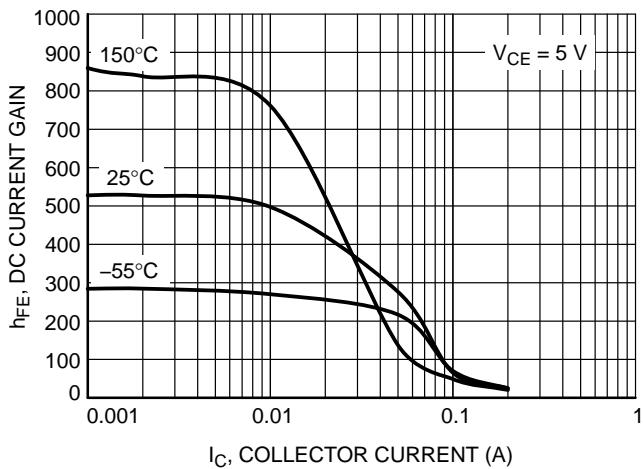


Figure 29. DC Current Gain vs. Collector Current

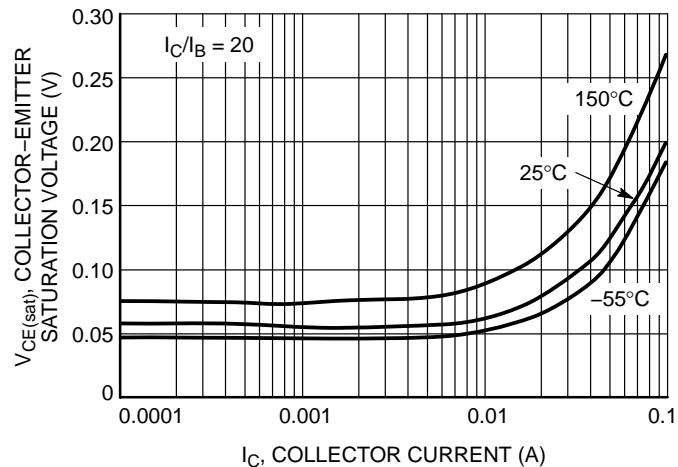


Figure 30. Collector Emitter Saturation Voltage vs. Collector Current

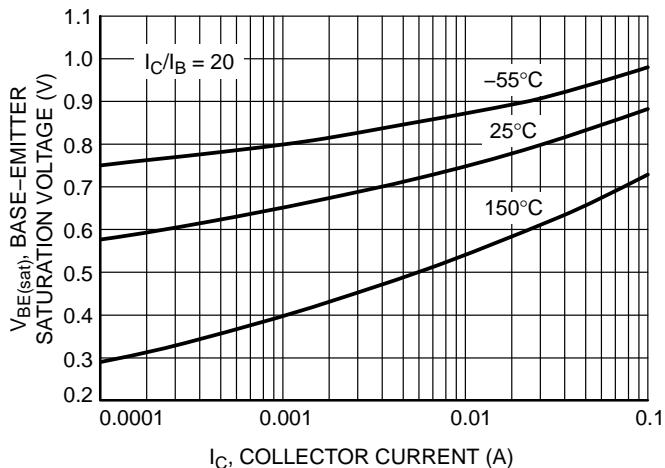


Figure 31. Base Emitter Saturation Voltage vs. Collector Current

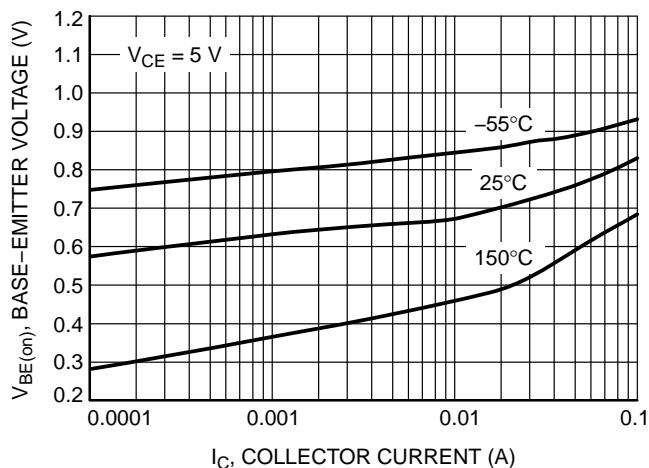


Figure 32. Base Emitter Voltage vs. Collector Current

BC846, BC847, BC848

BC847C, BC848C

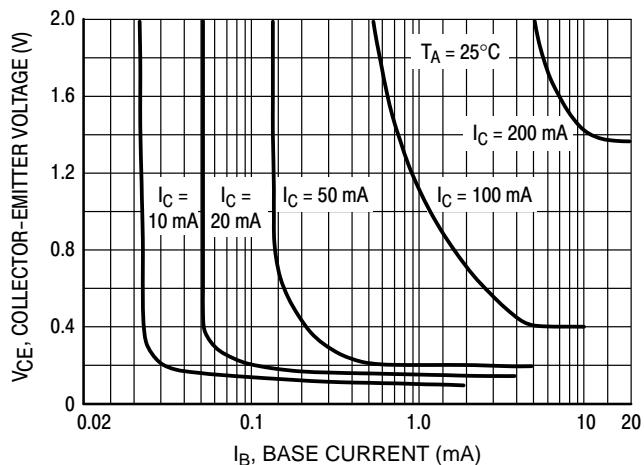


Figure 33. Collector Saturation Region

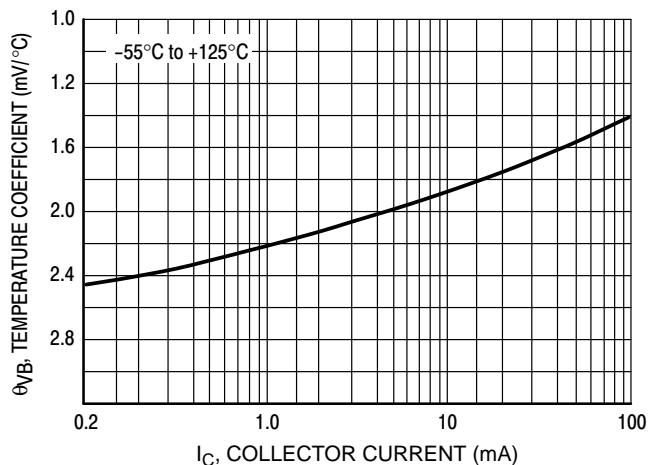


Figure 34. Base-Emitter Temperature Coefficient

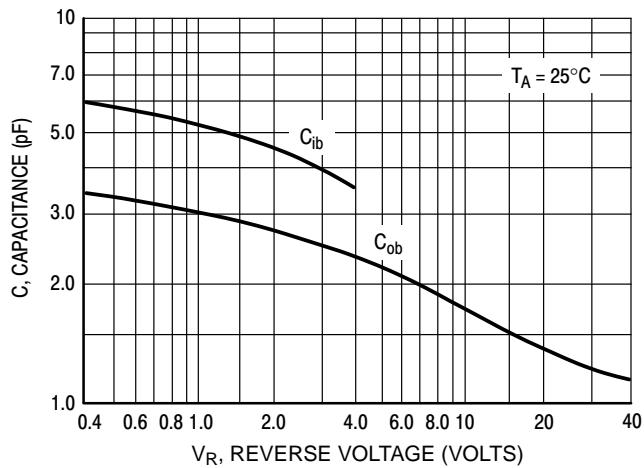


Figure 35. Capacitances

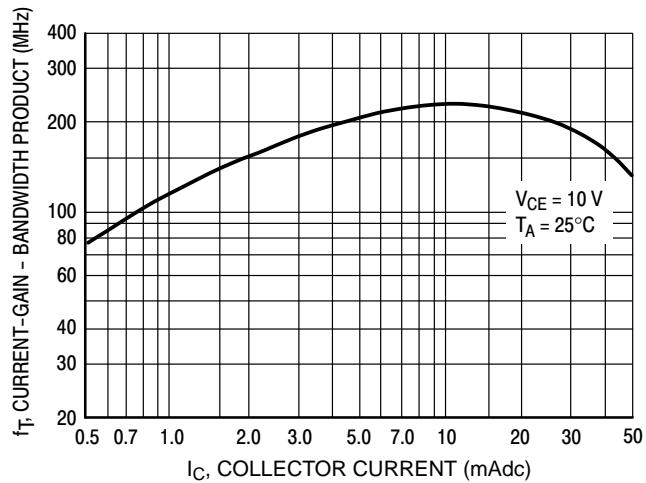


Figure 36. Current-Gain – Bandwidth Product

BC846, BC847, BC848

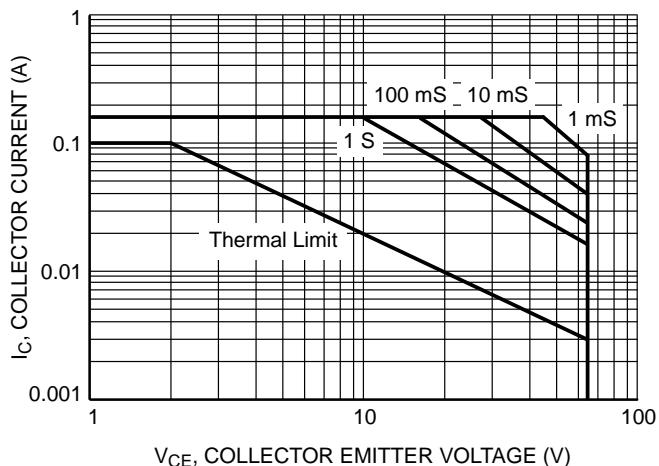


Figure 37. Safe Operating Area for
BC846A, BC846B

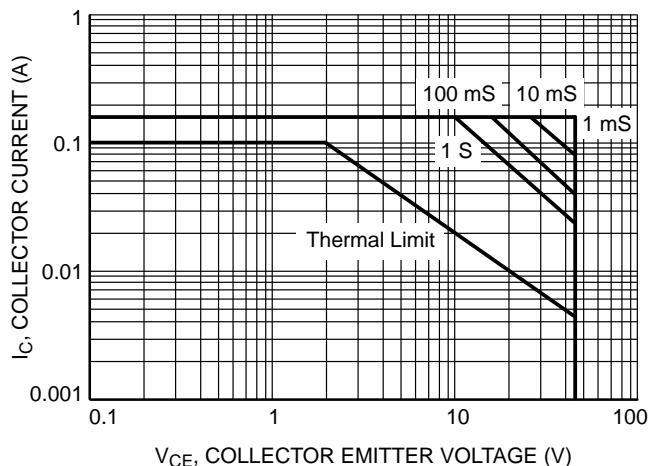


Figure 38. Safe Operating Area for
BC847A, BC847B, BC847C

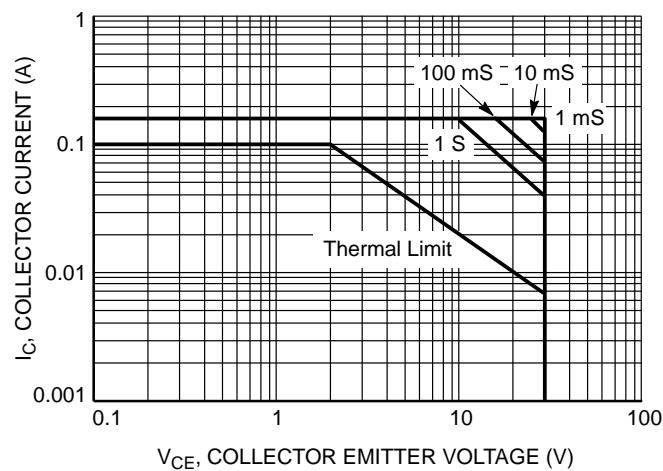


Figure 39. Safe Operating Area for
BC848A, BC848B, BC848C

BC846, BC847, BC848

DEVICE ORDERING AND SPECIFIC MARKING INFORMATION

| Device | Specific Marking Code | Package | Shipping [†] |
|----------------|----------------------------|------------------------------|-----------------------|
| BC846BWT1G | 1B 1E 1F 1G 1G | SC-70 (SOT-323) (Pb-Free) | 3,000 / Tape & Reel |
| SBC846BWT1G* | | | 3,000 / Tape & Reel |
| BC847AWT1G | | | 3,000 / Tape & Reel |
| SBC847AWT1G* | | | 3,000 / Tape & Reel |
| BC847BWT1G | | | 3,000 / Tape & Reel |
| SBC847BWT1G* | | | 3,000 / Tape & Reel |
| BC847CWT1G | | | 10,000 / Tape & Reel |
| SBC847CWT1G* | | | 3,000 / Tape & Reel |
| BC847CWT3G | | | 3,000 / Tape & Reel |
| SBC847CWT3G* | | | 3,000 / Tape & Reel |
| BC848BWT1G | 1K | | |
| NSVBC848BWT1G* | | | |
| BC848CWT1G | 1L | | |

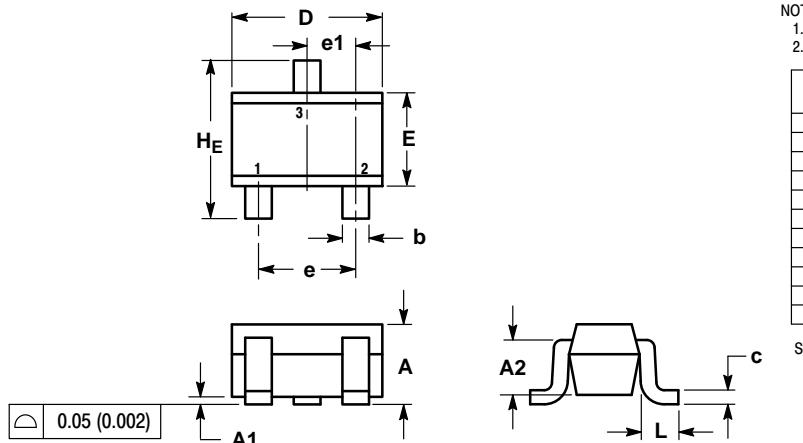
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

BC846, BC847, BC848

PACKAGE DIMENSIONS

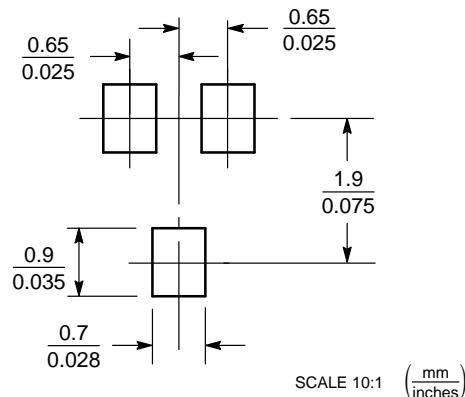
SC-70 (SOT-323) CASE 419-04 ISSUE N



| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|-----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A2 | 0.70 REF | | | 0.028 REF | | |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 |
| c | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 |
| D | 1.80 | 2.10 | 2.20 | 0.071 | 0.083 | 0.087 |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 |
| e | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e1 | 0.65 BSC | | | 0.026 BSC | | |
| L | 0.20 | 0.38 | 0.56 | 0.008 | 0.015 | 0.022 |
| H_E | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 |

STYLE 3:
 PIN 1. BASE
 2. Emitter
 3. Collector

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
 P.O. Box 5163, Denver, Colorado 80217 USA
 Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
 Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
 Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
 USA/Canada

Europe, Middle East and Africa Technical Support:
 Phone: 421 33 790 2910
Japan Customer Focus Center
 Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.